

# Mono 3.2W Class D Amplifier with Integrated Input Coupling Capacitors

#### **General Description**

#### **Features**

The MAX98314 mono 3.2W Class D amplifier provides Class AB audio performance with Class D efficiency. This device offers five selectable gain settings (0dB, 3dB, 6dB, 9dB, and 12dB) set by a single gain-select input (GAIN).

Active emissions limiting (AEL) edge rate and overshoot control circuitry and a filterless spread-spectrum modulation (SSM) scheme greatly reduce EMI and eliminate the need for output filtering found in traditional Class D devices.

The IC's low 0.95mA at 3.7V, 1.2mA at 5.0V guiescent current extends battery life in portable applications.

Highly linear, integrated input coupling capacitors (C<sub>IN</sub>) reduce solution size and provide excellent THD+N, PSRR, and CMRR performance at low frequencies vs. standard Class D amplifiers using external input capacitors.

The IC is available in a small 9-bump, 0.3mm pitch WLP (1.0mm x 1.0mm x 0.80mm) package and is specified over the -40°C to +85°C extended temperature range.

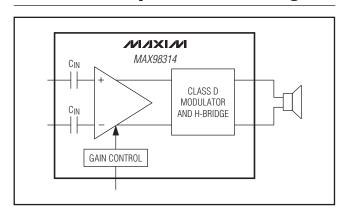
#### **Applications**

Mobile Phones Portable Audio Notebook Computers MP3 Players **Netbook Computers VoIP Phones** 

Ordering Information appears at end of data sheet.

- ♦ Integrated Input Coupling Capacitors with **Excellent Linearity** 
  - $\Leftrightarrow$  f<sub>C</sub> = 100Hz (6dB)
  - $\Leftrightarrow$  f<sub>C</sub> = 200Hz (12dB)
- **♦ Low Quiescent Current** 
  - ♦ 0.95mA at 3.7V
  - ♦ 1.2mA at 5.0V
- ♦ Delivers High Output Power at 10% THD+N
  - $\Rightarrow$  3.2W into  $4\Omega$ ,  $V_{PVDD} = 5V$
  - $\Rightarrow$  960mW into 8 $\Omega$ , V<sub>PVDD</sub> = 3.7V
- ♦ Ultra-Low Noise: 19µV
- **♦** Eliminates Output Filtering Requirement
  - ♦ Spread Spectrum and Active Emissions Limiting
- ♦ Click-and-Pop Suppression
- **♦ Thermal and Overcurrent Protection**
- **♦ Low Current Shutdown Mode**
- ♦ Small, Space-Saving Package

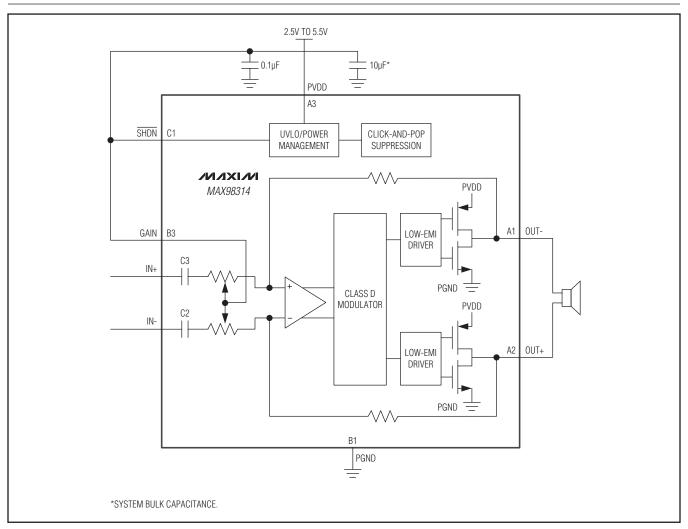
#### Simplified Block Diagram



For related parts and recommended products to use with this part, refer to: www.maxim-ic.com/MAX98314.related

# **Mono 3.2W Class D Amplifier** with Integrated Input Coupling Capacitors

### Functional Diagram/Typical Application Circuit



# **Mono 3.2W Class D Amplifier** with Integrated Input Coupling Capacitors

#### **ABSOLUTE MAXIMUM RATINGS**

| PVDD, IN+, IN-, SHDN, GAIN to PGND           | 0.3V to +6V |
|--|-------------|
| OUT+, OUT- to PGND                           |             |
| Continuous Current In/Out of PVDD, PGND, OUT | 750mA       |
| Continuous Input Current (all other pins)    | ±20mA       |
| Duration of Short Circuit Between            |             |
| OUT_ to PVDD, PGND                           | Continuous  |
| Between OUT+ and OUT- Pins                   | Continuous  |

| Continuous Power Dissipation ( $T_A = +70^{\circ}C$ ) for | or Multilayer Board |
|---|---------------------|
| WLP (derate 10.64mW/°C above +70°C)                       | 851mW               |
| Junction Temperature                                      | +150°C              |
| Operating Temperature Range                               | 40°C to +85°C       |
| Storage Temperature Range                                 | 65°C to +150°C      |
| Soldering Temperature (reflow)                            | +260°C              |
|   |                     |

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

#### PACKAGE THERMAL CHARACTERISTICS (Note 1)

WI P

Junction-to-Ambient Thermal Resistance (θ,JA) ....... 102°C/W Junction-to-Case Thermal Resistance (θ<sub>JC</sub>)......47°C/W

Note 1: Package thermal resistances were obtained using the method described in JEDEC specification JESD51-7, using a fourlayer board. For detailed information on package thermal considerations, refer to www.maxim-ic.com/thermal-tutorial.

#### **ELECTRICAL CHARACTERISTICS**

 $(V_{PVDD} = V_{\overline{SHDN}} = V_{GAIN} = 5V, V_{PGND} = 0V, A_V = 6dB (GAIN = PVDD), R_L = \infty, R_L connected between OUT+ to OUT-, AC measure$ ment bandwidth 20Hz to 22kHz,  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A = +25$ °C.) (Note 2, 3)

| PARAMETER                 | SYMBOL            | CONDITIONS            |  | MIN                             | TYP   | MAX                  | UNITS |      |
|---------------------------|-------------------|-----------------------|--|---------------------------------|-------|----------------------|-------|------|
| AMPLIFIER CHARACTERISTIC  | S                 | •                     |  |                                 |       |                      |       |      |
| Supply Voltage Range      | V <sub>PVDD</sub> | Guarantee             | ed by PSRR te  | st                              | 2.5   |                      | 5.5   | V    |
| Undervoltage Lockout      | UVLO              | PVDD falli            | ng   |                                 |       | 1.8                  | 2.2   | V    |
| Quiescent Current         | 1                 | V <sub>PVDD</sub> = 5 | 5V   |                                 |       | 1.2                  | 1.8   | mA   |
| Quiescent Current         | I <sub>PVDD</sub> | $V_{PVDD} = 3$        | 3.7V   |                                 |       | 0.95                 |       | IIIA |
| Shutdown Supply Current   | ISHDN             | V <sub>SHDN</sub> =   | $0V, T_A = +25^\circ$  | C                               |       | < 0.1                | 10    | μA   |
| Turn-On Time              | t <sub>ON</sub>   |                       |  |                                 |       | 3.7                  | 10    | ms   |
| Bias Voltage              | V <sub>BIAS</sub> |                       |  |                                 |       | V <sub>PVDD</sub> /2 | )     | V    |
|                           |                   |                       | GAIN conne   | cted to PGND                    | 11.75 | 12                   | 12.25 |      |
|                           |                   | $A_V$ $f = 1kHz$      |  | cted to PGND<br>kΩ ±5% resistor | 8.75  | 9                    | 9.25  |      |
| Voltage Gain              | A <sub>V</sub>    |                       | GAIN connected to PVDD  GAIN connected to PVDD  through 100kΩ ±5% resistor |                                 | 5.75  | 6                    | 6.25  | dB   |
|                           |                   |                       |  |                                 | 2.75  | 3                    | 3.25  |      |
|                           |                   |                       | GAIN uncon   | nected                          | -0.25 | 0                    | +0.25 |      |
| Input Capacitance         | C <sub>IN</sub>   | All gains             |  |                                 |       | 0.011                |       | μF   |
|                           |                   |                       |  | $A_V = 12dB$                    |       | 199                  |       |      |
| Highpass Corner Frequency |                   |                       |  | $A_V = 9dB$                     |       | 139                  |       |      |
|                           | f <sub>C</sub>    | -3dB dow              | n  | $A_V = 6dB$                     | 63    | 100                  | 189   | Hz   |
|                           |                   |                       |  | $A_V = 3dB$                     |       | 70                   |       |      |
|                           |                   |                       |  | $A_V = 0dB$                     |       | 50                   |       |      |

# **Mono 3.2W Class D Amplifier** with Integrated Input Coupling Capacitors

### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{PVDD} = V_{\overline{SHDN}} = V_{GAIN} = 5V, V_{PGND} = 0V, A_V = 6dB (GAIN = PVDD), R_L = \infty, R_L connected between OUT+ to OUT-, AC measurement bandwidth 20Hz to 22kHz, <math>T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .) (Note 2, 3)

| PARAMETER                      | SYMBOL                          | CONDITIONS   |                                      | MIN      | TYP                 | MAX  | UNITS |  |   |
|--------------------------------|---------------------------------|--|--------------------------------------|----------|---------------------|------|-------|--|---|
| Common-Mode Rejection Ratio    | CMRR                            | f <sub>IN</sub> = 1kHz, input referred                                       |                                      |          | 67                  |      | dB    |  |   |
| Output Offset Voltage          | Vos                             | $T_A = +25^{\circ}C \text{ (Note 4)}$  |                                      |          | ±1                  | ±3   | mV    |  |   |
| Click and Dan Laval            | voltage, $T_A = +25^{\circ}C$ , | Into shutdown  |                                      | -59      |                     | dDV/ |       |  |   |
| Click-and-Pop Level            | K <sub>CP</sub>                 | A-weighted, 32<br>samples per second,<br>T <sub>A</sub> = +25°C (Notes 4, 5) | Out of shutdown                      |          | -82                 |      | dBV   |  |   |
|                                |                                 | $V_{PVDD} = 2.5V \text{ to } 5.5V, T$  | A = +25°C                            | 70       | 90                  |      |       |  |   |
| Power-Supply Rejection Ratio   | PSRR                            |  | f = 217Hz                            |          | 74                  |      | dB    |  |   |
| (Note 4)                       | 1 01111                         | $V_{RIPPLE} = 200 \text{mV}_{P-P}$   | f = 1kHz                             |          | 72                  |      | ] ub  |  |   |
|                                |                                 |  | f = 20kHz                            |          | 49                  |      |       |  |   |
|                                |                                 | THD+N = 10%  | $V_{PVDD} = 5.0V$                    |          | 3.2                 |      | -     |  |   |
| Output Power                   |                                 | f = 1kHz   | $V_{PVDD} = 4.2V$                    |          | 2.2                 |      |       |  |   |
|                                |                                 | $R_L = 4\Omega + 33\mu H$  | $V_{PVDD} = 3.7V$                    |          | 1.7                 |      |       |  |   |
|                                |                                 | THD+N = 1%   | $V_{PVDD} = 5.0V$                    |          | 2.6                 |      |       |  |   |
|                                |                                 | f = 1kHz   | $V_{PVDD} = 4.2V$                    |          | 1.8                 |      |       |  |   |
|                                |                                 | $R_{L} = 4\Omega + 33\mu H$  | $V_{PVDD} = 3.7V$                    |          | 1.4                 |      |       |  |   |
|                                | P <sub>OUT</sub>                | $THD+N = 10\%$ $f = 1kHz$ $R_{L} = 8\Omega + 68\mu H$ $THD+N = 1\%$          | $V_{PVDD} = 5.0V$                    |          | 1.8                 |      | W     |  |   |
|                                |                                 |  | $V_{PVDD} = 4.2V$                    |          | 1.2                 |      |       |  |   |
|                                |                                 |  | $V_{PVDD} = 3.7V$                    |          | 0.96                |      |       |  |   |
|                                |                                 |  | $V_{PVDD} = 5.0V$                    |          | 1.4                 |      |       |  |   |
|                                |                                 |  |                                      | f = 1kHz | $V_{PVDD} = 4.2V$   |      | 1     |  | 1 |
|                                |                                 | $R_L = 8\Omega + 68\mu H$  | $V_{PVDD} = 3.7V$                    |          | 0.8                 |      | 1     |  |   |
| Total Harmonic Distortion Plus | TUD: N                          | £ 41.11-   | $R_L = 4\Omega,$<br>$P_{OUT} = 1W$   |          | 0.03                | 0.1  | 0/    |  |   |
| Noise                          | THD+N                           | $f_{IN} = 1kHz$  | $R_{L} = 8\Omega$ $P_{OUT} = 0.725W$ |          | 0.03                |      | - %   |  |   |
|                                |                                 |  | $A_V = 12dB$                         |          | 31                  |      |       |  |   |
|                                |                                 |  | $A_V = 9dB$                          |          | 26                  |      |       |  |   |
| Output Noise                   | V <sub>N</sub>                  | A-weighted (Note 4) $A_V = 6dB$  | 23                                   |          | - μV <sub>RMS</sub> |      |       |  |   |
|                                |                                 |  | $A_V = 3dB$                          |          | 21                  |      | 1     |  |   |
|                                |                                 |  | $A_V = 0dB$                          |          | 19                  | ,    | 1     |  |   |
| Efficiency                     | η                               | $R_L = 8\Omega$ , $P_{OUT} = 1.8W$ ,   | f = 1kHz                             |          | 93                  |      | %     |  |   |
| Oscillator Frequency           | fosc                            |  |                                      |          | 300                 |      | kHz   |  |   |
| Spread-Spectrum Bandwidth      |                                 |  |                                      |          | 20                  |      | kHz   |  |   |
| Current Limit                  |                                 |  |                                      |          | 2.8                 |      | А     |  |   |
| Thermal Shutdown Level         |                                 |  |                                      |          | 155                 |      | °C    |  |   |

# **Mono 3.2W Class D Amplifier** with Integrated Input Coupling Capacitors

#### **ELECTRICAL CHARACTERISTICS (continued)**

 $(V_{PVDD} = V_{\overline{SHDN}} = V_{GAIN} = 5V, \ V_{PGND} = 0V, \ A_{V} = 6dB \ (GAIN = PVDD), \ R_{L} = \infty, \ R_{L} \ connected \ between \ OUT+ \ to \ OUT-, \ AC \ measure-pvd \ AC \ meas$ ment bandwidth 20Hz to 22kHz,  $T_A = T_{MIN}$  to  $T_{MAX}$ , unless otherwise noted. Typical values are at  $T_A = +25$ °C.) (Note 2, 3)

| PARAMETER             | SYMBOL           | CONDITIONS                       | MIN | TYP | MAX | UNITS |
|-----------------------|------------------|----------------------------------|-----|-----|-----|-------|
| Thermal Hysteresis    |                  |                                  |     | 15  |     | °C    |
| DIGITAL INPUT (SHDN)  |                  |                                  |     |     |     |       |
| Input Voltage High    | V <sub>INH</sub> | V <sub>PVDD</sub> = 2.5V to 5.5V | 1.4 |     |     | V     |
| Input Voltage Low     | V <sub>INL</sub> | V <sub>PVDD</sub> = 2.5V to 5.5V |     |     | 0.4 | V     |
| Input Leakage Current |                  | $T_A = +25$ °C                   |     |     | ±1  | μΑ    |

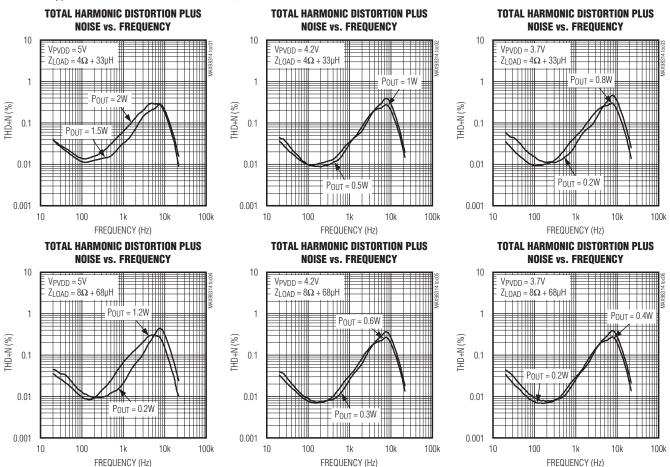
Note 2: All devices are 100% production tested at  $T_A = +25^{\circ}C$ . Specifications over temperature limits are guaranteed by design.

**Note 3:** Testing performed with a resistive load in series with an inductor to simulate an actual speaker load. For  $R_1 = 4\Omega$ ,  $L = 33\mu H$ . For  $R_1 = 8\Omega$ ,  $L = 68\mu H$ .

Note 4: Amplifier inputs AC-coupled to ground.

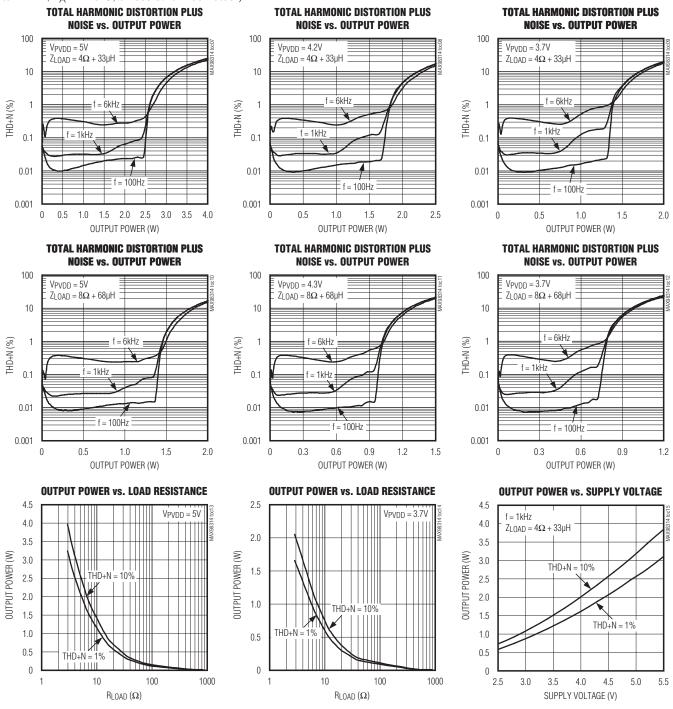
Note 5: Mode transitions controlled by SHDN control pin.

#### **Typical Operating Characteristics**



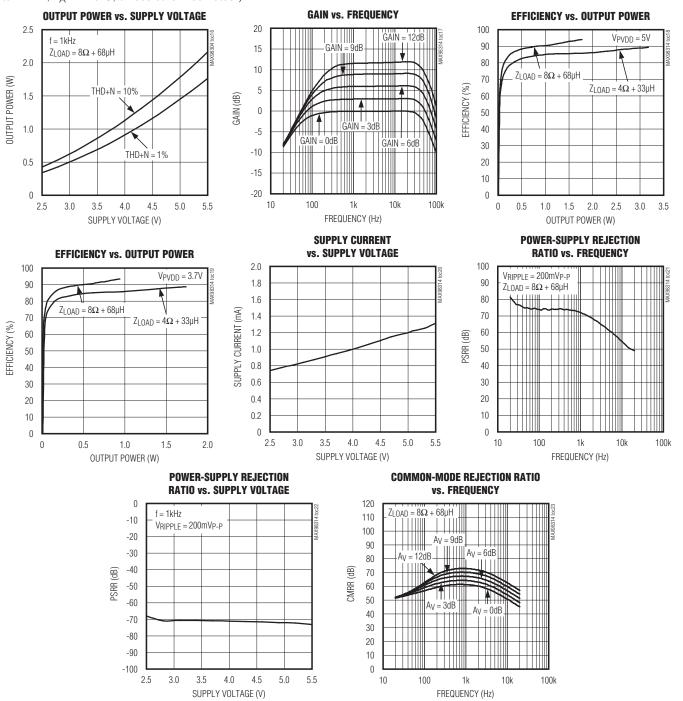
# **Mono 3.2W Class D Amplifier** with Integrated Input Coupling Capacitors

#### Typical Operating Characteristics (continued)



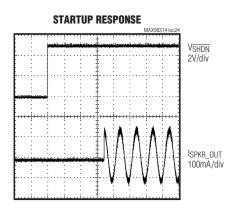
# **Mono 3.2W Class D Amplifier** with Integrated Input Coupling Capacitors

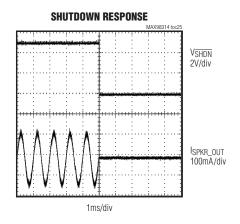
#### **Typical Operating Characteristics (continued)**

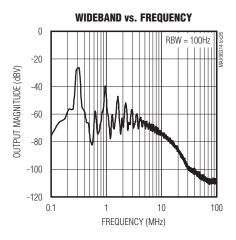


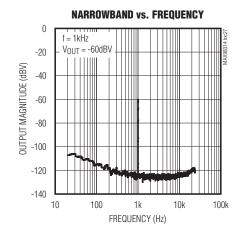
# **Mono 3.2W Class D Amplifier** with Integrated Input Coupling Capacitors

### **Typical Operating Characteristics (continued)**



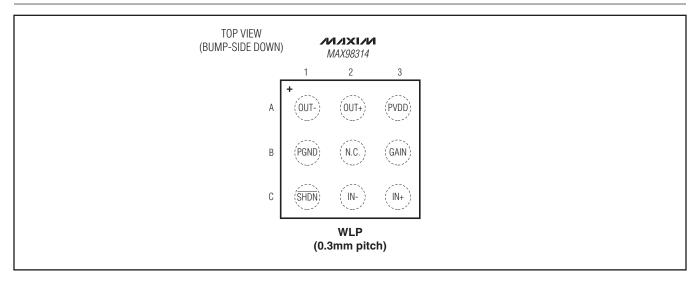






# **Mono 3.2W Class D Amplifier** with Integrated Input Coupling Capacitors

### **Pin Configuration**



### **Pin Description**

| BUMP | NAME | FUNCTION   |
|------|------|--|
| A1   | OUT- | Negative Speaker Output  |
| A2   | OUT+ | Positive Speaker Output  |
| А3   | PVDD | Power Supply. Bypass PVDD with a 0.1µF and 10µF capacitor to PGND.         |
| B1   | PGND | Power Ground   |
| B2   | N.C. | No Connection. Can be left unconnected or connected to PGND.               |
| B3   | GAIN | Gain Select. See <u>Table 1</u> for GAIN settings.                         |
| C1   | SHDN | Active-Low Shutdown Input. Drive SHDN low to place the device in shutdown. |
| C2   | IN-  | Inverting Audio Input  |
| С3   | IN+  | Noninverting Audio Input   |

# Mono 3.2W Class D Amplifier with Integrated Input Coupling Capacitors

#### **Detailed Description**

The MAX98314 features low quiescent current, a lowpower shutdown mode, comprehensive click-and-pop suppression, and excellent RF immunity.

The IC offers Class AB audio performance with Class D efficiency in a minimal board-space solution. The Class D amplifier features spread-spectrum modulation, edgerate, and overshoot control circuitry that offers significant improvements to switch-mode amplifier radiated emissions.

The amplifier features click-and-pop suppression that reduces audible transients on startup and shutdown. The amplifier additionally includes thermal overload and short-circuit protection.

Highly linear, integrated input coupling capacitors (C<sub>IN</sub>) reduce solution size and provide excellent THD+N, PSRR, and CMRR performance at low frequencies vs. standard Class D amplifiers using external input capacitors.

#### Class D Speaker Amplifier

The IC's filterless Class D amplifier offers much higher efficiency than Class AB amplifiers. The high efficiency of a Class D amplifier is due to the switching operation of the output stage transistors. Any power loss associated with the Class D output stage is mostly due to the I<sup>2</sup>R loss of the MOSFET on-resistance and quiescent switching current overhead.

#### Ultra-Low EMI Filterless Output Stage

Traditional Class D amplifiers require the use of external LC filters, or shielding, to meet electromagnetic interference (EMI) regulation standards. Maxim's patented active emissions limiting edge-rate control circuitry and spread-spectrum modulation reduces EMI emissions, while maintaining up to 93% efficiency.

The spread-spectrum modulation mode flattens wideband spectral components, while proprietary techniques ensure that the cycle-to-cycle variation of the switching period does not degrade audio reproduction or efficiency. The IC's spread-spectrum modulator randomly varies the switching frequency by ±20kHz around the center frequency (300kHz). Above 10MHz, the wideband spectrum looks like noise for EMI purposes (Figure 1).

#### **Amplifier Current Limit**

If the output current of the speaker amplifier exceeds the current limit (2.8A typ), the IC disables the outputs for approximately 100µs. At the end of 100µs, the outputs are reenabled. If the fault condition still exists, the IC continues to disable and reenable the outputs until the fault condition is removed.

#### **Selectable Amplifier Gain**

The IC offers five programmable gain settings, selectable by a single gain input (GAIN).

**Table 1. GAIN Selection** 

| GAIN PIN   | MAXIMUM GAIN (dB) |
|--|-------------------|
| Connect to PGND                                  | 12                |
| Connect to PGND through $100 k\Omega \pm 5\%$    | 9                 |
| Connect to PVDD                                  | 6                 |
| Connect to PVDD through $100 \text{k}\Omega$ ±5% | 3                 |
| Unconnected                                      | 0                 |

#### Integrated Input Coupling Capacitors (CIN)

The IC integrates two 0.011µF input coupling capacitors, CIN. The input coupling capacitors, in conjunction with the amplifier's internal input resistance (R<sub>IN</sub>), form a firstorder highpass filter that removes the DC bias from the incoming signal. These capacitors allow the amplifier to bias the signal to an optimum DC level.

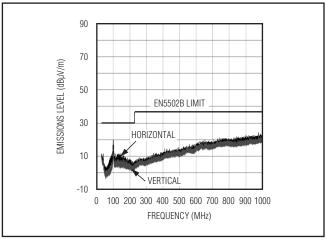


Figure 1. EMI Performance with 60cm of Speaker Cable, No Output Filter

# **Mono 3.2W Class D Amplifier** with Integrated Input Coupling Capacitors

Assuming zero source impedance, the -3dB corner frequency, f-3dB, is:

#### $f_{-3dB} = 1/2\pi R_{IN}C_{IN}$ [Hz]

The 100ppm/V voltage coefficient of the integrated input coupling capacitor results in excellent low-frequency THD+N performance. Figure 2 illustrates the superior linearity of the IC's integrated input coupling capacitors compared to a similar amplifier with external 0.01µF X7R and X5R 0402 input coupling capacitors.

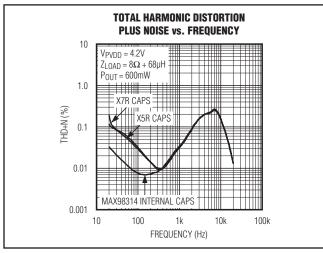


Figure 2. Low-Frequency THD+N Performance

#### Shutdown

The IC features a low-power shutdown mode, drawing < 0.1µA (typ) of supply current. Drive SHDN low to put the IC into shutdown.

#### **Click-and-Pop Suppression**

The speaker amplifier features Maxim's comprehensive click-and-pop suppression. During startup, the clickand-pop suppression circuitry reduces any audible transient sources internal to the device. When entering shutdown, the differential speaker outputs ramp down to PGND quickly and simultaneously.

#### **Applications Information**

#### Filterless Class D Operation

Traditional Class D amplifiers require an output filter. The filter adds cost and size, and decreases efficiency and THD+N performance. The IC's filterless modulation scheme does not require an output filter.

Because the switching frequency of the IC is well beyond the bandwidth of most speakers, voice coil movement due to the switching frequency is very small. Use a speaker with a series inductance > 10 $\mu$ H. Typical 8 $\Omega$ speakers exhibit series inductances in the 20µH to 100µH range.

#### Speaker Amplifier Power-Supply Input (PVDD)

PVDD powers the speaker amplifier and ranges from 2.5V to 5.5V. Bypass PVDD with a 0.1µF and 10µF capacitor to PGND. Apply additional bulk capacitance at the device if long input traces between PVDD and the power source are used.

#### **Layout and Grounding**

Proper layout and grounding are essential for optimum performance. Good grounding improves audio performance and prevents switching noise from coupling into the audio signal.

Use wide, low-resistance output traces. As the load impedance decreases, the current drawn from the device increases. At higher current, the resistance of the output traces decrease the power delivered to the load. For example, if 2W is delivered from the device output to a  $4\Omega$  load through  $100m\Omega$  of total speaker trace, 1.904W is delivered to the speaker. If power is delivered through  $10m\Omega$  of total speaker trace, 1.99W is delivered to the speaker. Wide output, supply, and ground traces also improve the power dissipation of the device.

The IC is inherently designed for excellent RF immunity. For best performance, add ground fills around all signal traces on top or bottom PCB layers.

# **Mono 3.2W Class D Amplifier** with Integrated Input Coupling Capacitors

#### **WLP Applications Information**

For the latest application details on WLP construction, dimensions, tape carrier information, PCB techniques, bump-pad layout, and recommended reflow temperature profile, as well as the latest information on reliability testing results, refer to Application Note 1891: Wafer-Level Packaging (WLP) and Its Applications. Figure 3 shows the dimensions of the WLP balls used on the IC.

#### **Ordering Information**

| PART         | TEMP RANGE     | PIN-PACKAGE |
|--------------|----------------|-------------|
| MAX98314EWL+ | -40°C to +85°C | 9 WLP       |

<sup>+</sup>Denotes a lead(Pb)-free/RoHS-compliant package.

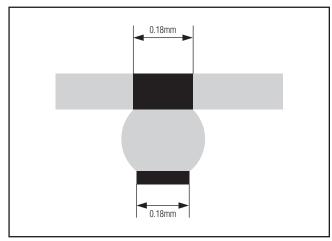


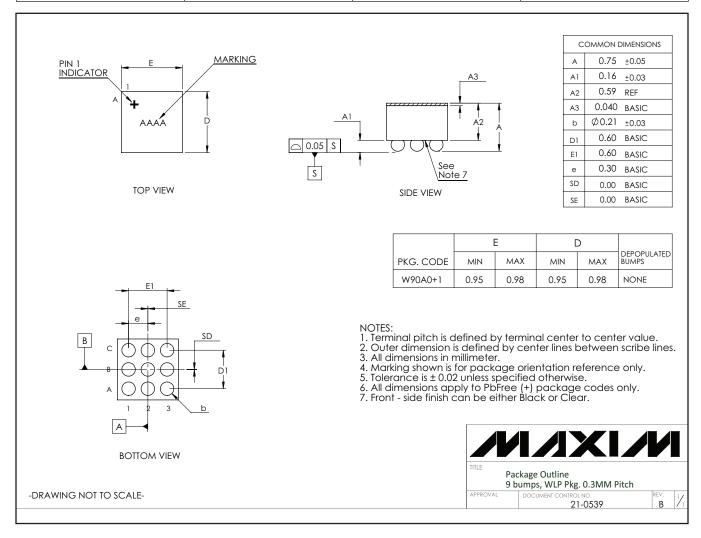
Figure 3. WLP Ball Dimensions

# **Mono 3.2W Class D Amplifier** with Integrated Input Coupling Capacitors

#### **Package Information**

For the latest package outline information and land patterns (footprints), go to www.maxim-ic.com/packages. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

| PACKAGE TYPE        | PACKAGE CODE | OUTLINE NO.    | LAND PATTERN NO.               |
|---------------------|--------------|----------------|--------------------------------|
| 9 WLP (0.3mm pitch) | W90A0+1      | <u>21-0539</u> | Refer to Application Note 1891 |



# Mono 3.2W Class D Amplifier with Integrated Input Coupling Capacitors

### **Revision History**

| REVISION<br>NUMBER | REVISION DATE | DESCRIPTION     | PAGES<br>CHANGED |
|--------------------|---------------|-----------------|------------------|
| 0                  | 11/11         | Initial release | _                |

Maxim cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim product. No circuit patent licenses are implied. Maxim reserves the right to change the circuitry and specifications without notice at any time. The parametric values (min and max limits) shown in the Electrical Characteristics table are guaranteed. Other parametric values quoted in this data sheet are provided for guidance.